

APPLICATIONS

- High Power Drives.
- High Voltage Power Supplies.
- DC Motor Control.

FEATURES

- Double Side Cooling.
- High Surge Capability.
- High Mean Current.
- Fatigue Free.

VOLTAGE RATINGS

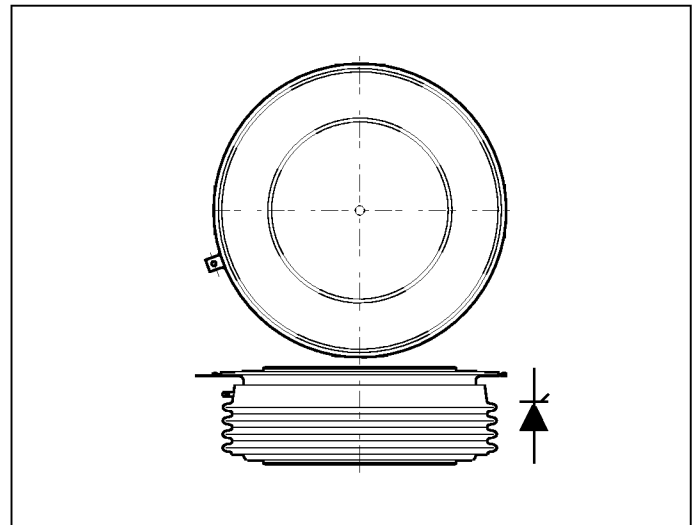
Type Number	Repetitive Peak Voltages V_{DRM} V_{RRM}	Conditions
DCR1474SY18	1800	$T_{vj} = 0^\circ \text{ to } 125^\circ\text{C}$, $I_{DRM} = I_{RRM} = 250\text{mA}$, $V_{DRM}, V_{RRM} t_p = 10\text{ms}$, $V_{DSM} \text{ \& } V_{RSM} =$ $V_{DRM} \text{ \& } V_{RRM} + 100\text{V}$ Respectively
DCR1474SY17	1700	
DCR1474SY16	1600	
DCR1474SY15	1500	
DCR1474SY14	1400	

Lower voltage grades available.

KEY PARAMETERS

V_{DRM}	1800V
$I_{T(AV)}$	2785A
I_{TSM}	61200A
dV/dt^*	1000V/ μs
dI/dt	300A/ μs

*Higher dV/dt selections available



Outline type code: Y. See package outline for further information.

CURRENT RATINGS

Symbol	Parameter	Conditions	Max.	Units
Double Side Cooled				
$I_{T(AV)}$	Mean on-state current	Half wave resistive load, $T_{case} = 80^\circ\text{C}$	2785	A
$I_{T(RMS)}$	RMS value	$T_{case} = 80^\circ\text{C}$	4370	A
I_T	Continuous (direct) on-state current	$T_{case} = 80^\circ\text{C}$	3750	A
Single Side Cooled (Anode side)				
$I_{T(AV)}$	Mean on-state current	Half wave resistive load, $T_{case} = 80^\circ\text{C}$	1750	A
$I_{T(RMS)}$	RMS value	$T_{case} = 80^\circ\text{C}$	2745	A
I_T	Continuous (direct) on-state current	$T_{case} = 80^\circ\text{C}$	2170	A

SURGE RATINGS

Symbol	Parameter	Conditions	Max.	Units
I_{TSM}	Surge (non-repetitive) on-state current	10ms half sine; $T_{case} = 125^{\circ}C$ $V_R = 50\% V_{RRM} - 1/4$ sine	49.0	kA
I^2t	I^2t for fusing		12.0×10^6	A ² s
I_{TSM}	Surge (non-repetitive) on-state current	10ms half sine; $T_{case} = 125^{\circ}C$ $V_R = 0$	61.2	kA
I^2t	I^2t for fusing		18.75×10^6	A ² s

THERMAL AND MECHANICAL DATA

Symbol	Parameter	Conditions		Min.	Max.	Units
$R_{th(j-c)}$	Thermal resistance - junction to case	Double side cooled	dc	-	0.0095	°C/W
		Single side cooled	Anode dc	-	0.019	°C/W
			Cathode dc	-	0.019	°C/W
$R_{th(c-h)}$	Thermal resistance - case to heatsink	Clamping force 43.0kN with mounting compound	Double side	-	0.002	°C/W
			Single side	-	0.004	°C/W
T_{vj}	Virtual junction temperature	On-state (conducting)		-	135	°C
		Reverse (blocking)		-	125	°C
T_{stg}	Storage temperature range			-55	125	°C
-	Clamping force			38.0	47.0	kN

DYNAMIC CHARACTERISTICS

Symbol	Parameter	Conditions		Typ.	Max.	Units
I_{RRM}/I_{DRM}	Peak reverse and off-state current	At V_{RRM}/V_{DRM} , $T_{case} = 125^{\circ}C$		-	250	mA
dV/dt	Maximum linear rate of rise of off-state voltage	To 67% V_{DRM} $T_j = 125^{\circ}C$.		-	1000	V/ μs
dI/dt	Rate of rise of on-state current	From 67% V_{DRM} to 1000A Gate source 20V, 10 Ω $t_r \leq 0.5\mu s$ to 1A, $T_j = 125^{\circ}C$	Repetitive 50Hz	-	150	A/ μs
			Non-repetitive	-	300	A/ μs
$V_{T(TO)}$	Threshold voltage	At $T_{vj} = 125^{\circ}C$		-	0.92	V
r_T	On-state slope resistance	At $T_{vj} = 125^{\circ}C$		-	0.09	m Ω
t_{gd}	Delay time	$V_D = 67\% V_{DRM}$, Gate source 30V, 15 Ω $t_r \leq 0.5\mu s$, $T_j = 25^{\circ}C$		-	2.5	μs
t_q	Turn-off time	$I_T = 1000A$, $t_p = 1ms$, $T_j = 125^{\circ}C$, $V_R = 50V$, $dI_{RR}/dt = 2A/\mu s$, $V_{DR} = 67\% V_{DRM}$, $dV_{DR}/dt = 8V/\mu s$ linear		200	-	μs
I_L	Latching current	$T_j = 25^{\circ}C$, $V_D = 5V$		300	1000	mA
I_H	Holding current	$T_j = 25^{\circ}C$, $R_{g-k} = \infty$		-	500	mA

GATE TRIGGER CHARACTERISTICS AND RATINGS

Symbol	Parameter	Conditions	Max.	Units
V_{GT}	Gate trigger voltage	$V_{DRM} = 5V$, $T_{case} = 25^{\circ}C$	4.0	V
I_{GT}	Gate trigger current	$V_{DRM} = 5V$, $T_{case} = 25^{\circ}C$	400	mA
V_{GD}	Gate non-trigger voltage	At V_{DRM} , $T_{case} = 125^{\circ}C$	0.25	V
V_{FGM}	Peak forward gate voltage	Anode positive with respect to cathode	30	V
V_{FGN}	Peak forward gate voltage	Anode negative with respect to cathode	0.25	V
V_{RGM}	Peak reverse gate voltage		5	V
I_{FGM}	Peak forward gate current	Anode positive with respect to cathode	30	A
P_{GM}	Peak gate power	See table, fig.4	150	W
$P_{G(AV)}$	Mean gate power		10	W

CURVES

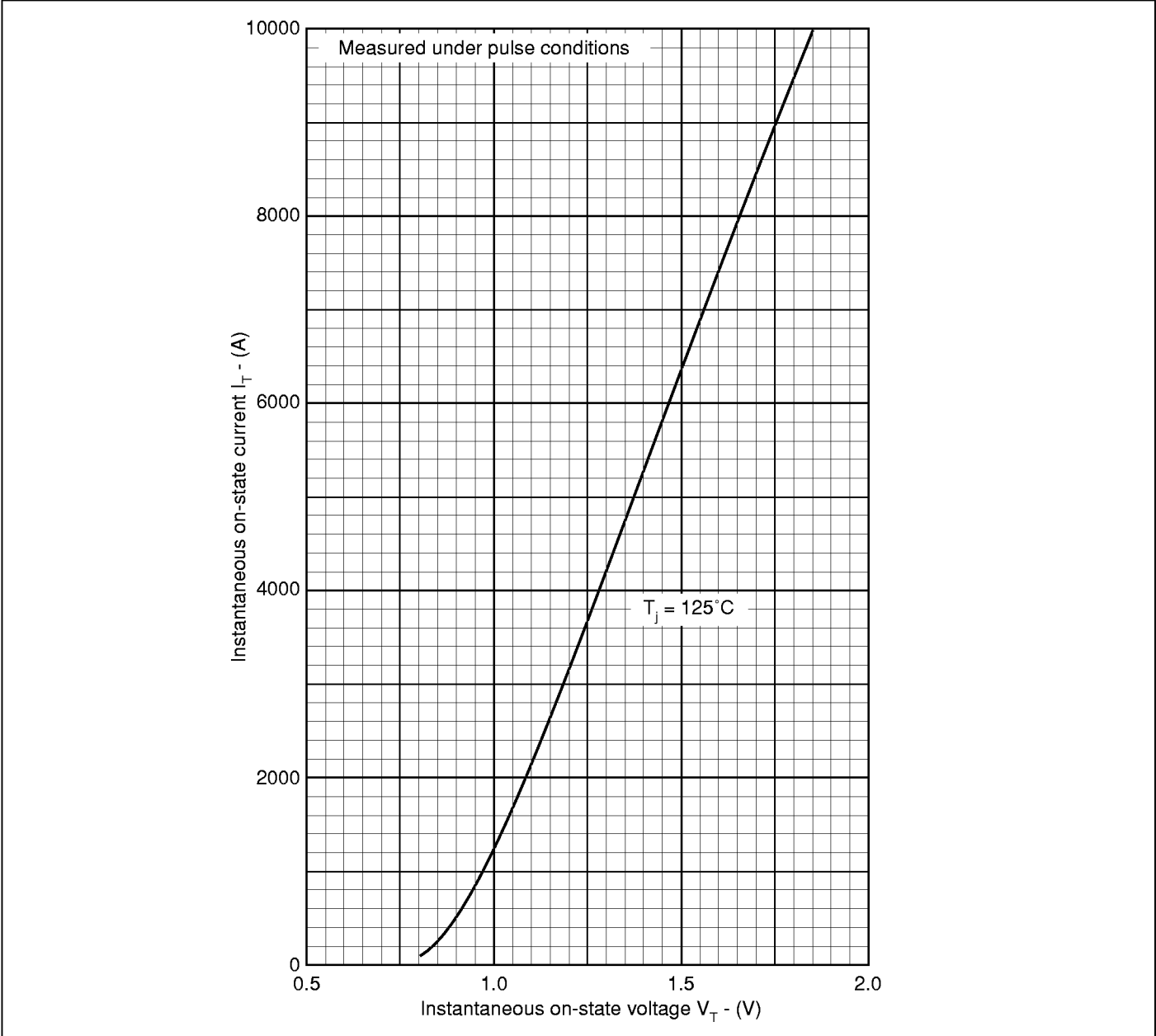


Fig.1 Maximum (limit) on-state characteristics

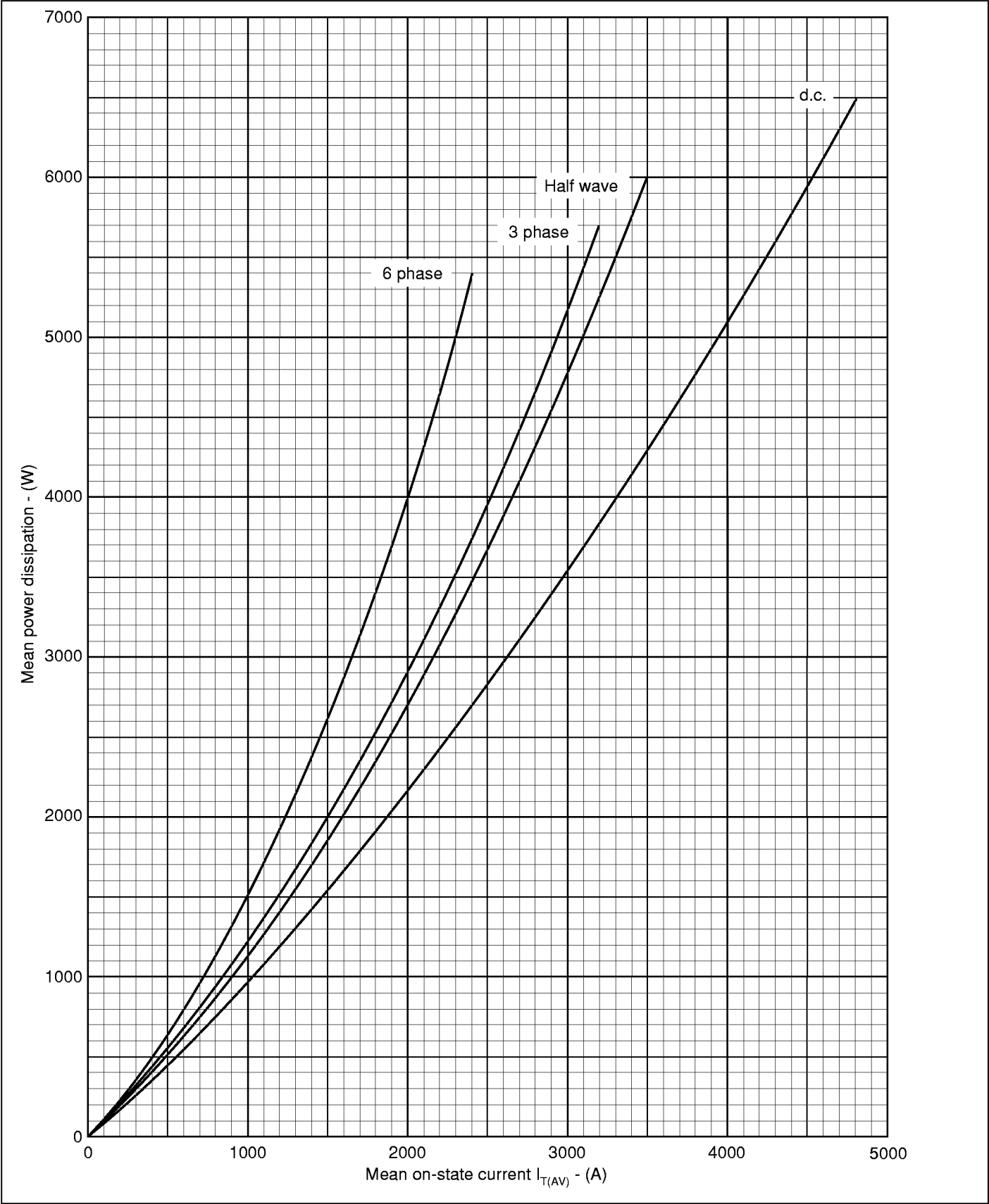


Fig.2 Dissipation curves

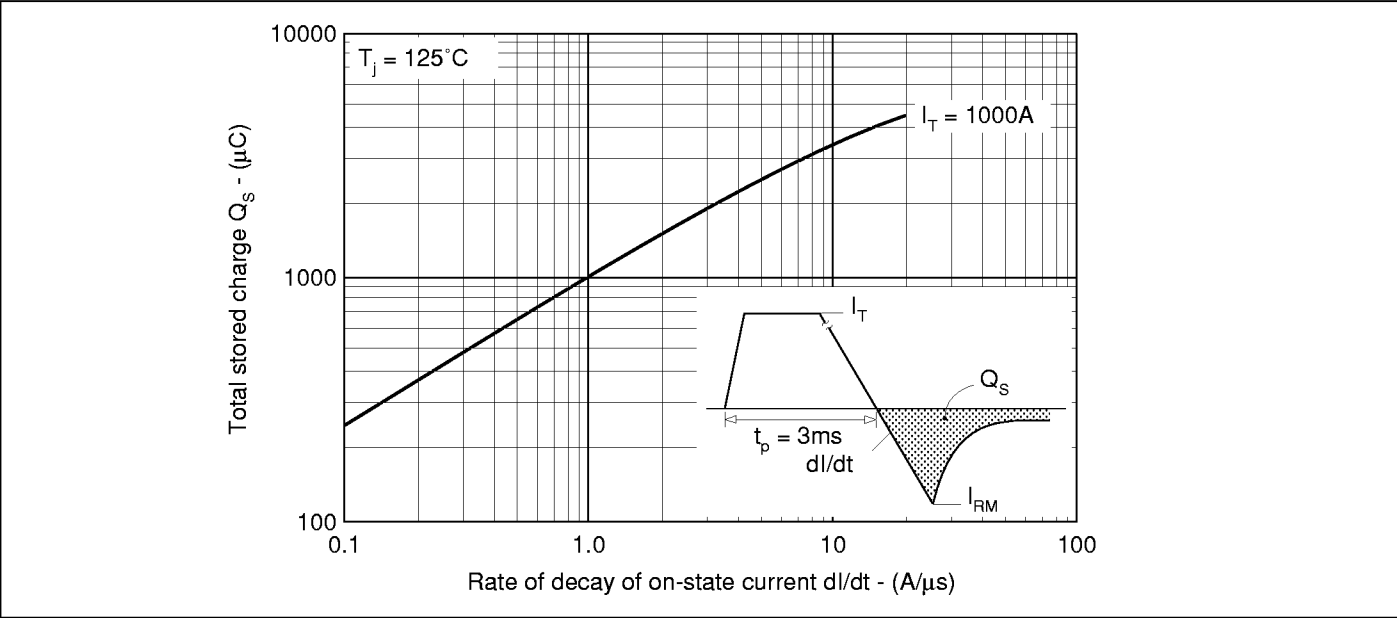


Fig.3 Stored charge

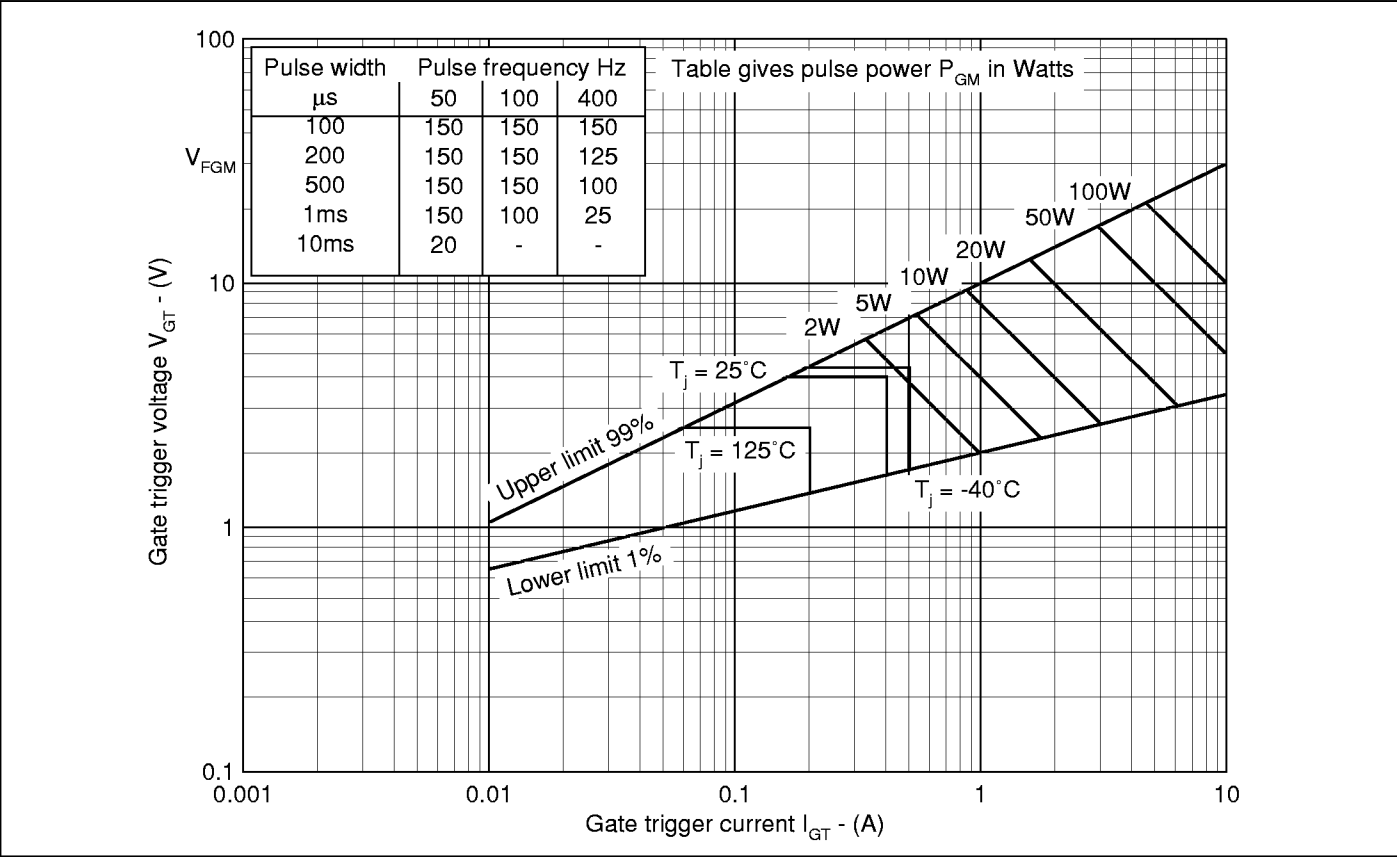


Fig.4 Gate characteristics

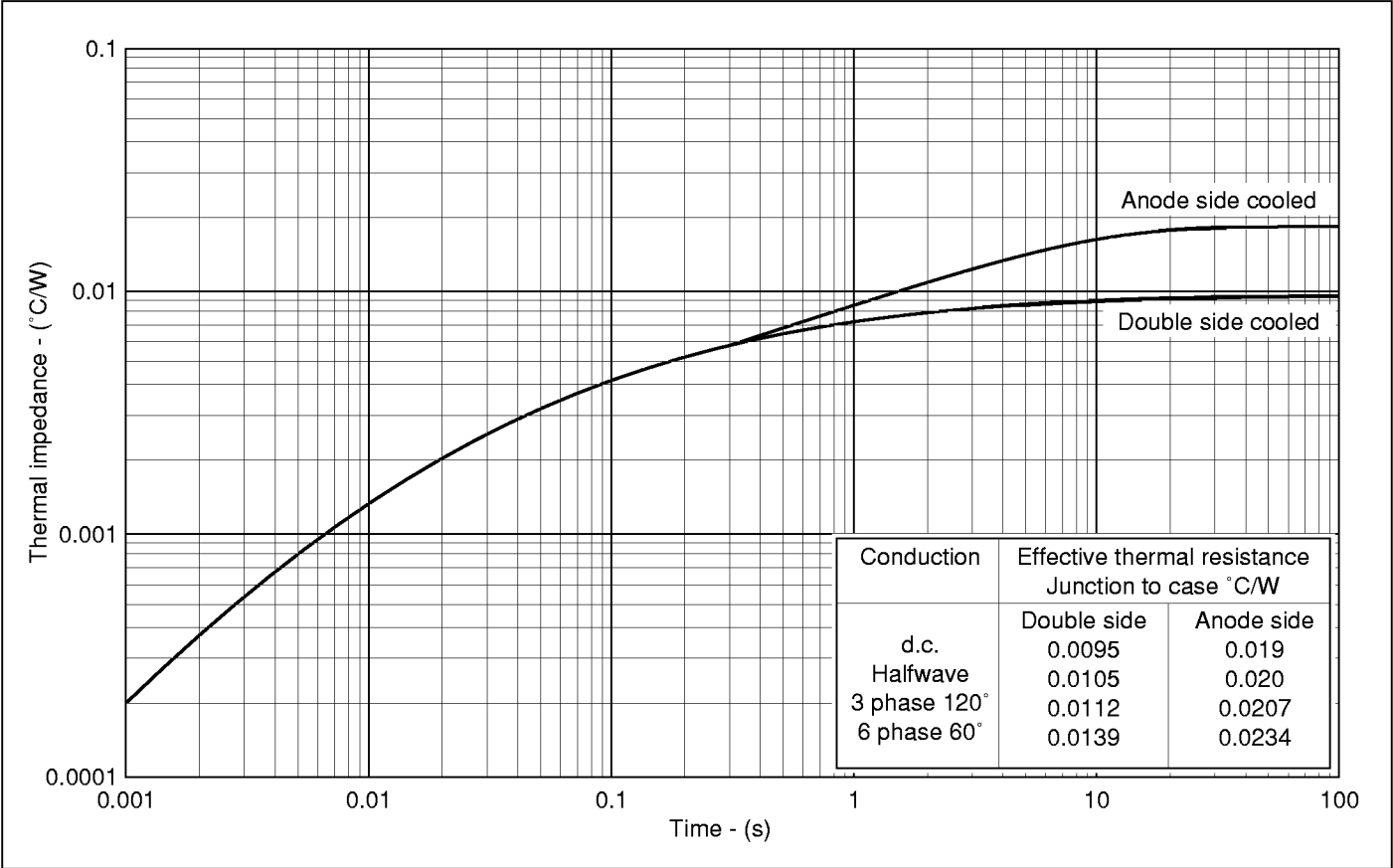


Fig.5 Maximum (limit) transient thermal impedance - junction to case

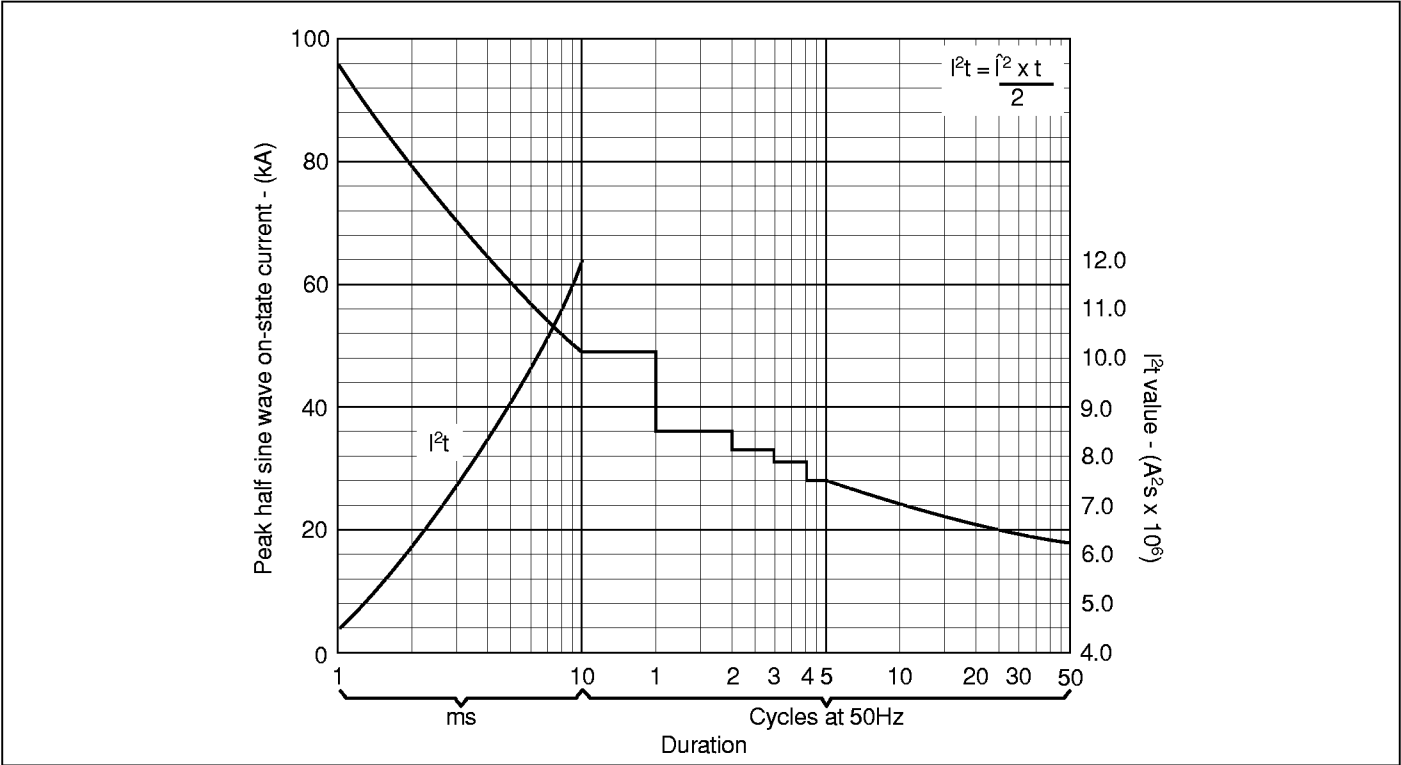
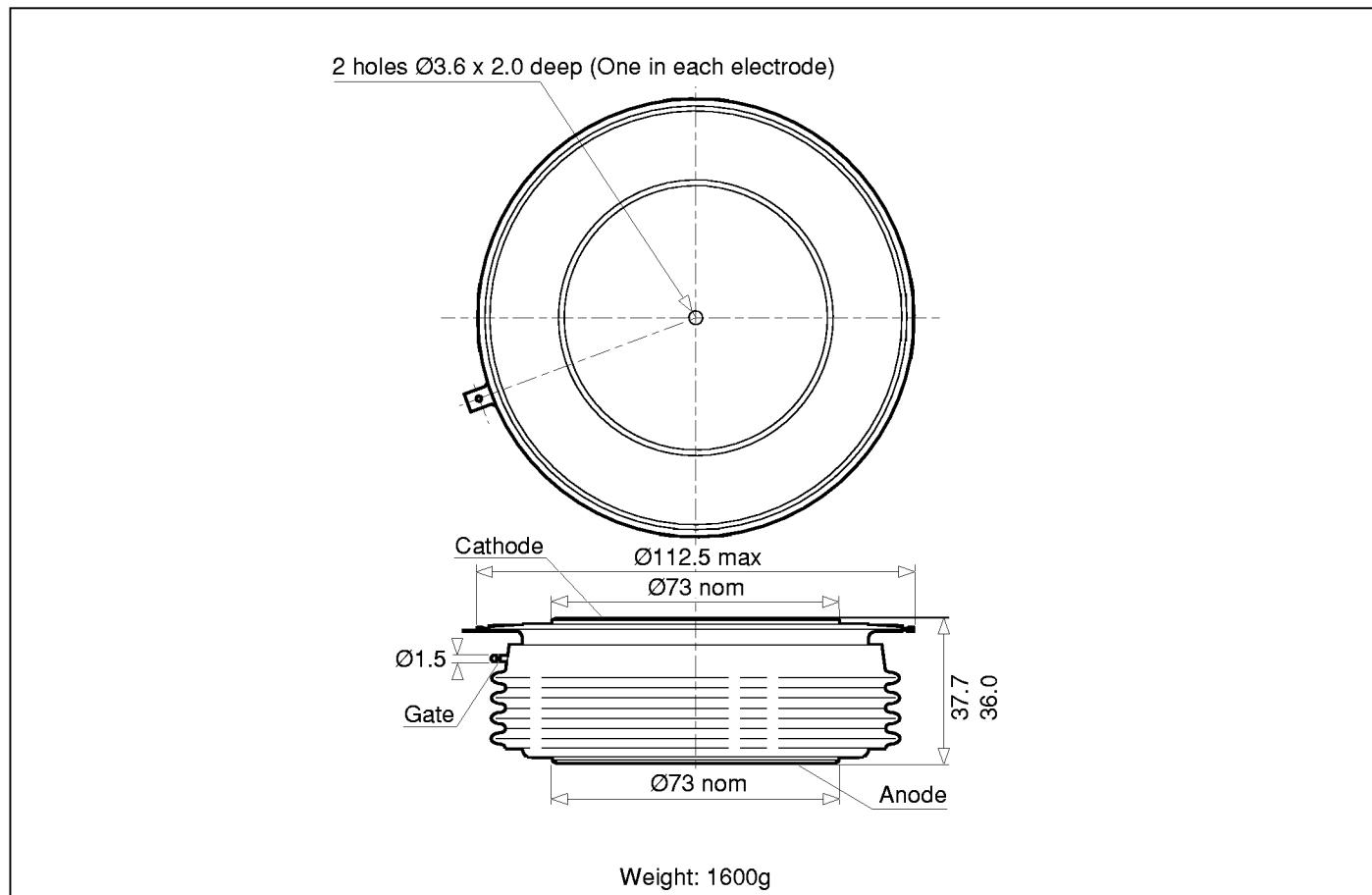


Fig.6 Surge (non-repetitive) on-state current vs time (with 50% V_{RRM} at T_{case} 125°C)

DCR1474SY

PACKAGE OUTLINE - Y

For further package information, please contact your local Customer Service Centre. All dimensions in mm, unless stated otherwise. DO NOT SCALE.



HEADQUARTERS OPERATIONS

MITEL SEMICONDUCTOR

Cheney Manor, Swindon,
Wiltshire SN2 2QW, United Kingdom.
Tel: (01793) 518000
Fax: (01793) 518411

MITEL SEMICONDUCTOR

1500 Green Hills Road,
Scotts Valley, California 95066-4922
United States of America.
Tel (408) 438 2900
Fax: (408) 438 5576/6231

Internet: <http://www.gpsemi.com>

POWER PRODUCT CUSTOMER SERVICE CENTRES

- **FRANCE, BENELUX & SPAIN.** Les Ulis Cedex. Tel: (1) 69 18 90 00. Fax: (1) 64 46 54 50.
- **GERMANY.** München. Tel: 089 41 95 080. Fax: 089 41 95 08 55.
- **NORTH AMERICA.** Dedham. Tel: (781) 251 0126. Fax: (781) 251 0106.
- **UNITED KINGDOM.** Lincoln. Tel: (01522) 500500. Fax: (01522) 510550.

These are supported by Agents and Distributors in major countries world-wide.

© Mitel Corporation 1998 Publication No. DS4649-4 Issue No. 4.2 March 1998

TECHNICAL DOCUMENTATION – NOT FOR RESALE. PRINTED IN UNITED KINGDOM

This publication is issued to provide information only which (unless agreed by the Company in writing) may not be used, applied or reproduced for any purpose nor form part of any order or contract nor to be regarded as a representation relating to the products or services concerned. No warranty or guarantee express or implied is made regarding the capability, performance or suitability of any product or service. The Company reserves the right to alter without prior notice the specification, design or price of any product or service. Information concerning possible methods of use is provided as a guide only and does not constitute any guarantee that such methods of use will be satisfactory in a specific piece of equipment. It is the user's responsibility to fully determine the performance and suitability of any equipment using such information and to ensure that any publication or data used is up to date and has not been superseded. These products are not suitable for use in any medical products whose failure to perform may result in significant injury or death to the user. All products and materials are sold and services provided subject to the Company's conditions of sale, which are available on request.

All brand names and product names used in this publication are trademarks, registered trademarks or trade names of their respective owners.